



CLOCK GENERATOR WITH FRACTIONAL-N PLL & INTEGRATED VCO, 125 - 3000 MHz

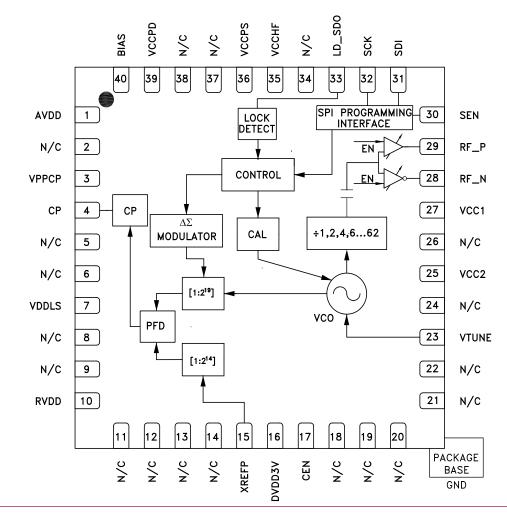
Typical Applications

- 10G/40G/100G Optical Modules, Transponders, Line Cards
- OTN and SONET/SDH Applications
- 1G/10G Ethernet Line Cards
- High Frequency Processor Clocks
- Any Frequency Clock Generation
- Low Jitter SAW Oscillator Replacement
- Fiber Channel Interface Clocks
- Cellular/4G Infrastructure
- DDS Replacement
- Optical Modules, Transponders, Line Cards

Functional Diagram

Features

Frequency Range: 125 - 3000 MHz 78 fs RMS Jitter Generation (Typical) Exceeds G.8251 & GR-253-CORE Jitter Specifications -165 dBc/Hz Phase Noise floor Maximum Phase Detector Rate 100 MHz Figure of Merit (FOM) -227 dBc/Hz 24-Bit Step Size, Resolution 3 Hz Typical Exact Frequency Mode Built-in Digital Self Test 40 Lead 6x6mm SMT Package: 36mm²





ROHS V

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General Description

The HMC1034LP6GE is a low-noise, wide-band clock generator IC with a fractional-N Phase Locked Loop (PLL) that features an integrated Voltage Controlled Oscillator (VCO). The device provides differential clock outputs between 125MHz and 3GHz range. The HMC1034LP6GE features low noise Phase Detector (PD) and Delta-Sigma modulator, capable of operating at up to 100MHz, permit wider loop-bandwidths with excellent spectral performance.

The HMC1034LP6GE features industry leading phase noise and jitter performance, across the operating range, that enable it to improve link level jitter performance, Bit-Error-Rates (BER) and eye diagram metrics. The superior noise floor (<-165dBc/Hz) makes the HMC1034LP6GE an ideal source for a variety of applications –such as clock references for high speed data converters, physical layer devices (PHY), serializer/deserializer (SERDES) circuits, FPGAs and processors. The HMC1034LP6GE can also be used as an LO for 10G/40G/100G optical modules and transponders, as well as primary reference clock for 10G/40G/100G line cards, and for jitter attenuation and frequency translation.

The differential output of the HMC1034LP6GE includes a 2-bit output amplitude control which may be set via the SPI serial programming interface, and an output Mute function. The Delta-Sigma Modulator of the HMC1034LP6GE features Hittite's Exact Frequency Mode, which enables users to generate output frequencies with close to 0Hz frequency error.

For theory of operation and register map refer to the "PLLs with Integrated VCOs - RF VCOs Operating Guide". To view the Operating Guide, please visit www.hittite.com and choose HMC1034LP6GE from the "Search by Part Number" pull down menu.

Parameter	Condition	Min.	Тур.	Max.	Units
RF Output Characteristics	· · · ·		•		
Output Frequency		125		3000	MHz
Output Specifications					
Output Voltage	Single-Ended Swing (peak-to- peak), 50 Ohm termination	0.25		1.35	Vpp
Output Amplitude Control	Gain Setting = 00, F=800 MHz		300		mVpp
	Gain Setting = 01, F=800 MHz		450		mVpp
	Gain Setting = 10, F=800 MHz		685		mVpp
	Gain Setting = 11, F=800 MHz		1.1		Vpp
Output Common Mode Voltage AC Coupling Recommended					
VCO Output Divider					
VCO RF Divider Range	1,2,4,6,8,,62	1		62	
PLL RF Divider Characteristics					
19-Bit N-Divider Range (Integer)	Max = 2 ¹⁹ - 1	16		524,287	
19-Bit N-Divider Range (Fractional)	Fractional Nominal Divide Ratio Varies (-3 / +4) Dynamically Max	20		524,283	
REF Input Characteristics					
Max Ref Input Frequency				350	MHz
Ref Input Voltage	AC Coupled ^[1]	1	2	3.3	Vp-p
Ref Input Capacitance				5	pF
14-Bit R-Divider Range		1		16,383	

Electrical Specifications, VPPCP, VDDLS, VCC1, VCC2 = 5V; RVDD, AVDD, DVDD3V, VCCPD, VCCHF, VCCPS = 3.3V Min & Max Specified across Temperature -40 °C to 85 °C

[1] Measured with 100 Ω external termination. See <u>Hittite PLL w/ Integraged VCOs Operating Guide</u> Reference Input Stage_section for more details. [2] Slew rate of greater or equal to 0.5 ns/V is recommended, see <u>PLL with Integrated RF VCOs Operating Guide</u> for more details. Frequency is guaranteed across process voltage and temperature from -40 °C to 85 °C.

[3] This maximum phase detector frequency can only be achieved if the minimum N value is respected. eg. In the case of fractional feedback mode, the maximum PFD rate = fvco/20 or 100 MHz, whichever is less.





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Electrical Specifications (Continued)

Parameter	Condition	Min.	Тур.	Max.	Units
Phase Detector (PD) [2]	· · · · · · · · · · · · · · · · · · ·				·
PD Frequency Fractional Mode B	[3]	DC		100	MHz
PD Frequency Fractional Mode A (and Register 6 [17:16] = 11)		DC		80	MHz
PD Frequency Integer Mode		DC		125	MHz
Charge Pump			•		
Output Current		0.02		2.54	mA
Charge Pump Gain Step Size			20		μA
PD/Charge Pump SSB Phase Noise	50 MHz Ref, Input Referred				
1 kHz			-143		dBc/Hz
10 kHz	Add 1 dB for Fractional		-150		dBc/Hz
100 kHz	Add 3 dB for Fractional		-153		dBc/Hz
RF_P, RF_N	· · · ·				
Output Rise Time	Measured from 20% to 80% of Output Signal, F=800 MHz Gain Setting = 00			150	ps
	Measured from 20% to 80% of Output Signal, F=800 MHz Gain Setting = 11			250	ps
Output Fall Time	Measured from 80% to 20% of Output Signal, F=800 MHz Gain Setting = 00			150	ps
	Measured from 80% to 20% of Output Signal, F=800MHz Gain Setting = 11			250	ps
Output Duty Cycle	Measured at 50% of Output Signal. F=800 MHz	40		60	%
Logic Inputs					
Vsw	Switching threshold for logic levels	40	50	60	% DVDD
Logic Outputs					
VOH Output High Voltage			DVDD		V
VOL Output Low Voltage			0		V
Output Impedance		100		200	Ω
Maximum Load Current				1.5	mA
Power Supply Voltages	· · · · ·		•		
3.3V Supplies	AVDD, VCCHF, VCCPS, VCCPD, RVDD,DVDD	3.0	3.3	3.5	V
5V Supplies	VPPCP, VDDCP, VCC1, VCC2	4.8	5	5.2	V
Power Supply Currents	· · · · · ·				
+5V Analog Charge Pump	VPPCP, VDDCP		8		mA
	fo/1 Mode VCC2		105		mA
+5V VCO Core & VCO Buffer	fo/N Mode VCC2		80		mA
	fo/1 Mode VCC1		25		mA
+5V VCO Divider & RF/PLL Buffer	fo/N Mode VCC1	80		100	mA
+3.3V	AVDD, VCCHF, VCCPS, VCCPD, RVDD, DVDD3V		52		mA
Power Down - Crystal Off	Reg 01h=0, Crystal Not Clocked		10		μA
Power Down - Crystal On, 100 MHz	Reg 01h=0, Crystal Clocked 100 MHz		5		mA





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Electrical Specifications (Continued)

Parameter	Condition	Min.	Тур.	Max.	Units
Power on Reset					•
Typical Reset Voltage on DVDD			700		mV
Minimum DVDD Voltage for No Reset		1.5			V
Power on Reset Delay			250		μs
Figure of Merit					
Floor Integer Mode	Normalized to 1 Hz		-230		dBc/Hz
Floor Fractional Mode	Normalized to 1 Hz		-227	İ	dBc/Hz
Flicker (Both Modes)	Normalized to 1 Hz		-268		dBc/Hz
Phase Jitter RMS	Measured at 622.08 MHz, Integration Bandwidth: 12 kHz to 20 MHz, 50 MHz reference, fractional mode		118		fs
Phase Jitter RMS	Measured at 800 MHz, Integration Bandwidth: 12 kHz to 20 MHz Charge Pump (CP) Current set at 2.54 mA, integer mode, 50 MHz reference		78		fs
Period Jitter RMS	Measured at 2.46 GHz, with a digital sampling oscilloscope and precision timebase module. The total measured RMS period jitter of 377 fs includes both the HMC1034 and instrument noise. Further calculations estimate HMC1034 RMS period jitter of <150 fs.		<377		fs





Figure 1. Typical Closed Loop Integer Phase Noise III

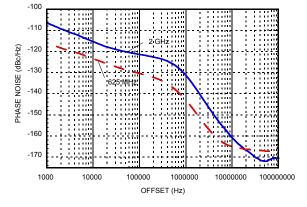


Figure 3. Free Running Phase Noise [3]

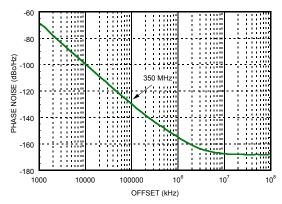


Figure 5. Figure of Merit

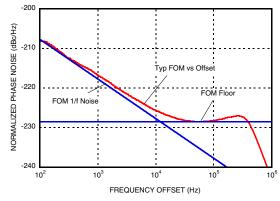


Figure 2. Typical Closed Loop Fractional Phase Noise ^[2]

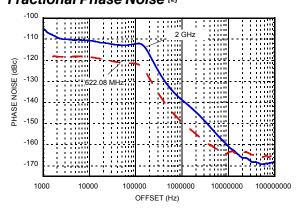


Figure 4. Integrated RMS Jitter [4]

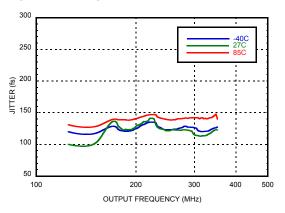
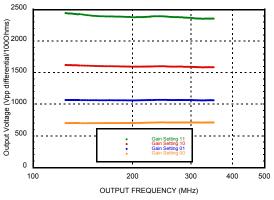


Figure 6. Typical Output Voltage



[1] The PN plot is measured with a 50 MHz Crystal Oscillator, Loop Filter Type 1 Refer to Loop Filter Configuration Table [2] The PN plot is measured with a 50 MHz Crystal Oscillator, Loop Filter Type 2 Refer to Loop Filter Configuration Table [3] Free Running Phase Noise @ fout = 350 MHz

[4] RMS Jitter data is measured in fractional mode with 100 kHz Loop bandwidth using 50 MHz reference frequency from 1 kHz to 20 MHz integration bandwidth.



ROHS V

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Figure 7. Reference Input Sensitivity, Square Wave 🕫

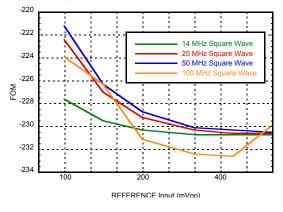


Figure 9. Output Rise Time

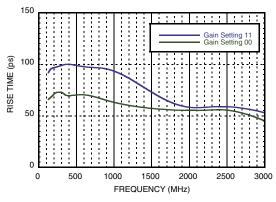


Figure 8. Reference Input Sensitivity Sinusoid Wave [6]

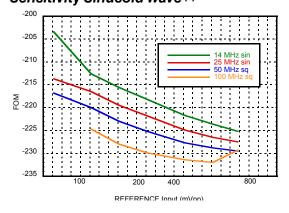
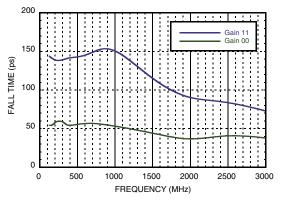


Figure 10. Output Fall Time



Loop Filter Configuration Table

Loop Filter Type ⁷	Loop Filter ⁸ BW (kHz)	Phase Margin	C1 (pF)	C2 (nF)	C3 (pF)	C4 (pF)	R2 (kΩ)	R3 (kΩ)	R4 (kΩ)	Loop Filter Design
Type 1	268	88°	3.9	15	N/A	N/A	2.7	0	0	
Type 2	135	58°	91	33	91	91	1.5	1	1	$\begin{array}{ccc} \begin{array}{c} \begin{array}{c} \begin{array}{c} \\ \\ \end{array} \end{array} \\ \begin{array}{c} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \\ \end{array} \\ \begin{array}{c} \\ \\ \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \\ \end{array} \\ \begin{array}{c} \\ \\ \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \\ \\ \end{array} $
Type 3	74	58°	150	27	220	220	0.82	1	1	

[5] Measured from a 50 Ω source with a 100 Ω external resistor termination. See <u>PLL with Integrated RF VCOs Operating Guide</u> Reference Input Stage section for more details. Full FOM performance up to maximum 3.3 Vpp input voltage.
[6] Measured from a 50 Ω source with a 100 Ω external resistor termination. See <u>PLL with Integrated RF VCOs Operating Guide</u> Reference Input Stage section for more details. Full FOM performance up to maximum 3.3 Vpp input voltage.
[7] Type 1 is the best choice for Integer Mode Operation only. Type 3 is used on the HMC1034 rev 1 evaluation board.
[8] Loop Filter designs based on VCO=3GHz, VCO gain = 15 MHz/V and charge pump current=2.5 mA.





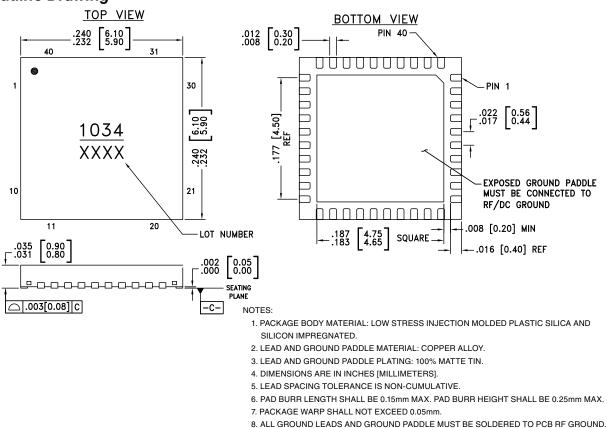
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Absolute Maximum Ratings

_
-0.3V to +3.6V
-0.3V to +5.5V
-0.3V to +5.5V
-40°C to +85°C
-65°C to 150°C
125 °C
20 °C/W
260°C
40 sec
Class 1B

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Outline Drawing



9. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

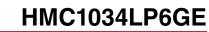
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[1]		
HMC1034LP6GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	<u>H1034</u> XXXX		
[1] 4-Digit lot number XXXX						



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Pin Descriptions

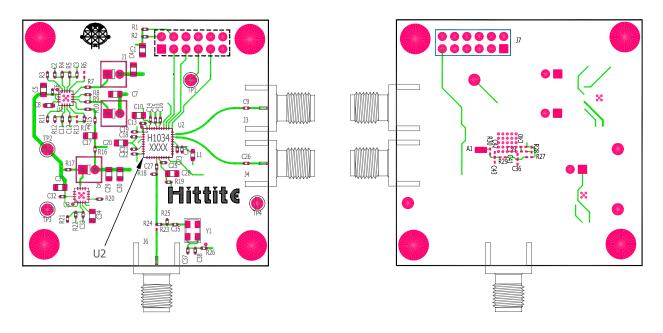
Pin Number	Function	Description	
1	AVDD	DC Power Supply for analog circuitry.	
2, 5, 6, 8, 9, 11 - 14, 18 - 22, 24, 26, 34, 37, 38	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	VPPCP	Power Supply for charge pump analog section	
4	СР	Charge Pump Output	
7	VDDLS	Power Supply for the charge pump digital section	
10	RVDD	Reference Supply	
15	XREFP	Reference Oscillator Input	
16	DVDD3V	DC Power Supply for Digital (CMOS) Circuitry	
17	CEN	Chip Enable. Connect to logic high for normal operation.	
23	VTUNE	VCO Varactor. Tuning Port Input.	
25	VCC2	VCO Analog Supply 2	
27	VCC1	VCO Analog Supply 1	
28	RF_N	Negative Output Signal (Differential)	
29	RF_P	Positive Output Signal (Differential) (Default = Off; Single-Ended Operation)	
30	SEN	PLL Serial Port Enable (CMOS) Logic Input	
31	SDI	PLL Serial Port Data (CMOS) Logic Input	
32	SCK	PLL Serial Port Clock (CMOS) Logic Input	
33	LD_SDO	Lock Detect, or Serial Data, or General Purpose (CMOS) Logic Output (GPO)	
35	VCCHF	DC Power Supply for Analog Circuitry	
36	VCCPS	DC Power Supply for Analog Prescaler	
39	VCCPD	DC Power Supply for Phase Detector	
40	BIAS	External bypass decoupling for precision bias circuits. Note: 1.920V ±20mV reference voltage (BIAS) is generated internally and cannot drive an external load. Must be measured with 10GΩ meter such as Agilent 34410A, normal 10MΩ DVM will read erroneously.	







Evaluation PCB



The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Evaluation PCB Schematic

To view this <u>Evaluation PCB Schematic</u> please visit <u>www.hittite.com</u> and choose HMC1034LP6GE from the "Search by Part Number" pull down menu to view the product splash page.

Evaluation Order Information

Item	Contents	Part Number
Evaluation PCB Only	HMC1034LP6GE Evaluation PCB	EVAL01-HMC1034LP6GE
Evaluation Kit	HMC1034LP6GE Evaluation PCB USB Interface Board 6' USB A Male to USB B Female Cable CD ROM (Contains User Manual, Evaluation PCB Schematic, Evaluation Software, Hittite PLL Design Software)	EKIT01-HMC1034LP6GE



HMC1034LP6GE Output Stage

A representative schematic for the HMC1034LP6GE output stage is given in Figure 11 below. The differential output buffer features adjustable amplitudes which can be set by the "Gain Setting" register values. The typical output amplitudes that correspond to each setting are provided in Figure 6.

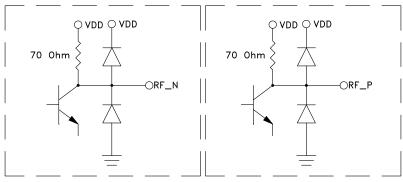


Figure 11. HMC1034LP6GE output stage

HMC1034LP6GE Application Information

The HMC1034LP6GE features a flexible Output Frequency Range (125MHz to 3000MHz), industry leading phase noise and phase jitter performance, excellent noise floor (<-170dBc/Hz), and a high level of integration. HMC1034LP6GE is ideal as a high frequency, low jitter processor clock, a clock source for high-frequency data converters or as a reference oscillator for Physical Layer Devices (PHY).

The HMC1034LP6GE can also be used as an LO for 10G/40G/100G optical modules and transponders, as a reference clock for 10G/40G/100G line cards, and for jitter attenuation and frequency translation. Synchronous Ethernet, SONET/SDH, and OTN applications often require jitter attenuation and frequency translation on the recovered line clock.

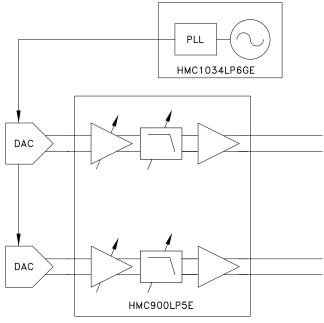


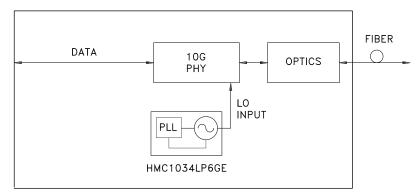
Figure 12. HMC1034LP6GE in a typical transmit chain

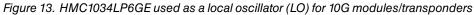




The HMC1034LP6GE can also be used as an LO for 10G optical modules and transponders (Figure 13), as a reference clock for 1G/10G line cards (Figure 14), and for jitter attenuation and frequency translation (Figure 15).

Synchronous Ethernet, SONET/SDH, and OTN applications often require jitter attenuation and frequency translation on the recovered line clock.





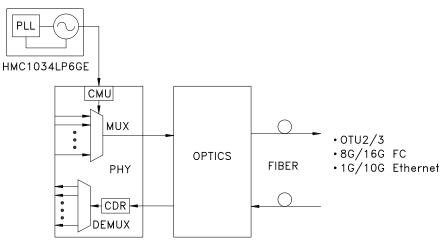


Figure 14. HMC1034LP6GE used as a reference clock for 1G/10G line cards





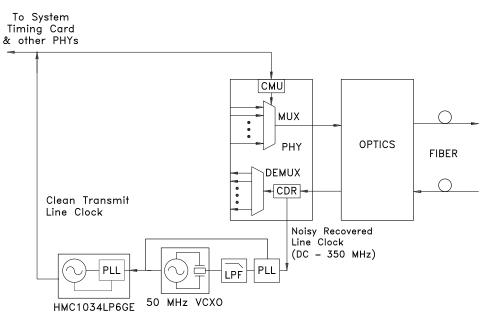


Figure 15. HMC1034LP6GE used in a jitter attenuation application for Synchronous Ethernet & Line Timing





Line and Reference Clock Rates

OTN	Line Rates (Gbps)	Typical Reference Clock Rates (MHz)		
OTU2	10.709	669.31	167.33	
OTU2e	11.095	693.44	173.36	
OTU1e	11.049	690.56	172.64	
OTU2f	11.317	707.31	176.83	
OTU1f	11.27	704.38	176.09	
OTU3	43.018	2688.63	672.16	
OTU4	111.809		1747.02	
OTU4v	127.156		1986.82	

SONET/SDH			
STS-192/STM-64	9.95328	622.08	155.52
STS-768/STM-256	39.81312	2488.32	622.08

Ethernet			
10GE LAN	10.3125		156.25
10GE WAN	9.95328	622.08	155.52
XAUI (4 x 3.125G)	3.125		156.25
40GE (4 x 10G)	10.3125		156.25
100GE (4 x 25G)	25.78125	805.66	156.25

Fibre Channel (FC)				
10GFC	10.52		164.38	
16GFC	14.025		212.5	
32GFC	28.5		425	





Notes: